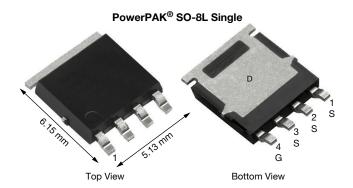


www.vishay.com

Vishay Siliconix

Automotive P-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY				
V _{DS} (V)	-40			
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.0070			
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.0100			
I _D (A)	-60			
Configuration	Single			

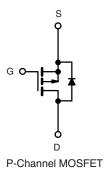
FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE



ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SQJ409EP (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS	(T _C = 25 °C, unless	s otherwise noted	d)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V_{DS}	-40	V	
Gate-source voltage		V_{GS}	± 20		
Continuous drain current	T _C = 25 °C ^a	1	-60		
	T _C = 125 °C	I _D	-42		
Continuous source current (diode conduction) ^a		I _S	-60	Α	
Pulsed drain current ^b		I _{DM}	-150		
Single pulse avalanche current		I _{AS}	-41		
Single pulse avalanche energy	L = 0.1 mH	E _{AS}	84	mJ	
Maximum power dissipation ^b	T _C = 25 °C	D	68	14/	
	T _C = 125 °C	P_{D}	22	W	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) d, e			260		

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient P	CB mount c	R_{thJA}	68	°C/W
Junction-to-case (drain)		R_{thJC}	2.2	C/VV

Notes

- a. Package limited
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (<u>www.vishay.com/doc?73257</u>). For PowerPAK SO-8L, the end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



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PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static						L		
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0, I _D = -250 μA		-40	-	-	.,	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$		-2.0	-2.5	V	
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = -40 V	-	-	-1		
Zero gate voltage drain current	I _{DSS}		V _{DS} = -40 V, T _J = 125 °C	-	-	-50	μΑ	
		$V_{GS} = 0 V$	V _{DS} = -40 V, T _J = 175 °C	-	-	-150		
On-state drain current ^a	I _{D(on)}	V _{GS} = -10 V	V _{DS} ≥ -5 V	-30	-	-	Α	
B :		V _{GS} = -10 V	I _D = -10 A	-	0.0058	0.0070	Ω	
	Б	V _{GS} = -10 V	I _D = -10 A, T _J = 125 °C	-	-	0.0106		
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -10 V	I _D = -10 A, T _J = 175 °C	-	-	0.0126		
		V _{GS} = -4.5 V	I _D = -6 A	-	0.0083	0.0100		
Forward transconductance b	9 _{fs}	V _{DS} =	-15 V, I _D = -10 A	-	54	-	S	
Dynamic ^b								
Input capacitance	C _{iss}		V _{DS} = -25 V, f = 1 MHz	-	8400	11 000	рF	
Output capacitance	C _{oss}	$V_{GS} = 0 V$		-	620	850		
Reverse transfer capacitance	C _{rss}				510	700	1	
Total gate charge ^c	Qg			-	170	260		
Gate-source charge c	Q_{gs}	V _{GS} = -10 V	$V_{DS} = -20 \text{ V}, I_{D} = -5 \text{ A}$	-	24	-	nC	
Gate-drain charge ^c	Q_{gd}	7		-	35	-		
Gate resistance	R _g	f = 1 MHz		0.50	1.08	1.70	Ω	
Turn-on delay time ^c	t _{d(on)}				23	35	ns	
Rise time ^c	t _r	V_{DD} = -20 V, R_L = 4 Ω $I_D \cong$ -5 A, V_{GEN} = -10 V, R_g = 1 Ω		=	18	30		
Turn-off delay time ^c	t _{d(off)}			-	75	120		
Fall time ^c	t _f	7			12	20		
Source-Drain Diode Ratings and Chara	acteristics ^b							
Pulsed current ^a	I _{SM}				-	-150	Α	
Forward voltage	V _{SD}	I _F = -10 A, V _{GS} = 0 V			-0.76	-1.2	V	
Body diode reverse recovery time	t _{rr}	I _F = -10 A, di/dt = 100 A/μs			39	90	ns	
Body diode reverse recovery charge	Q _{rr}			-	45	100	nC	
Reverse recovery fall time	ta			-	22	-	no	
Reverse recovery rise time	t _b			-	19	-	ns	
Body diode peak reverse recovery current	I _{RM(REC)}			-	-2.3	-	Α	

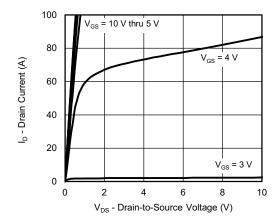
Notes

- f. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- g. Guaranteed by design, not subject to production testing
- h. Independent of operating temperature

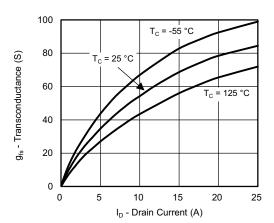
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



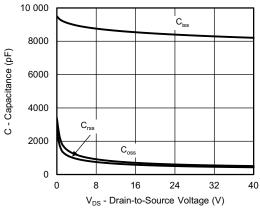
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



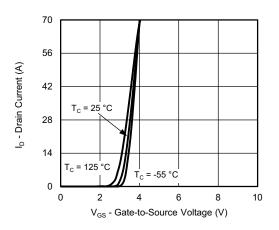
Output Characteristics



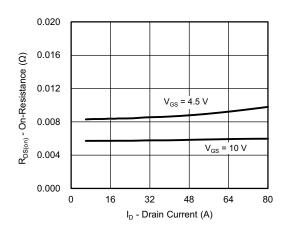
Transconductance



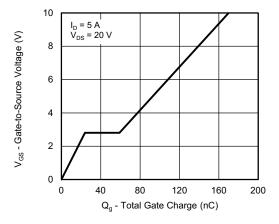
Capacitance



Transfer Characteristics



On-Resistance vs. Drain Current

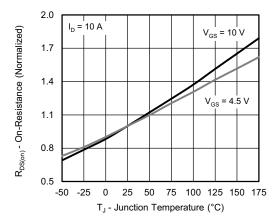


Gate Charge

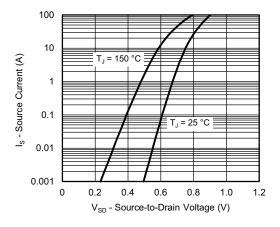
For technical questions, contact: automostechsu



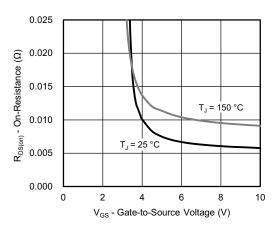
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



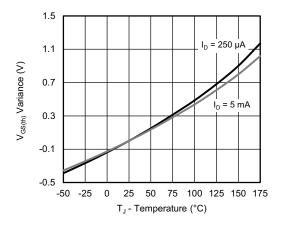
On-Resistance vs. Junction Temperature



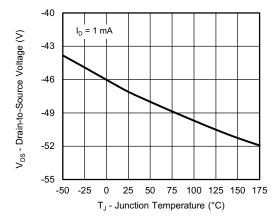
Source Drain Diode Forward Voltage



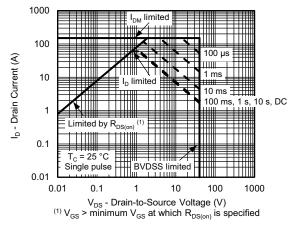
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



Drain-Source Breakdown vs. Junction Temperature

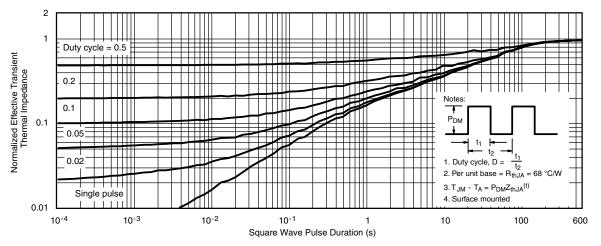


Safe Operating Area

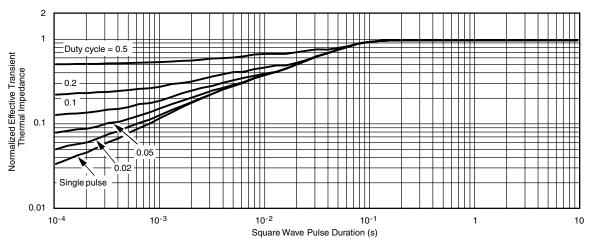
For technical questions, contact: automostech



THERMAL RATINGS (T_C = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?77707.



PowerPAK® SO-8L Case Outline 2



Vishay Siliconix

DIM	MILLIMETERS			INCHES				
DIM.	MIN.	NOM.	MAX.	MIN. NOM.		MAX.		
Α	1.00	1.07	1.14	0.039	0.042	0.045		
A1	0.00	-	0.127	0.00	-	0.005		
b	0.33	0.41	0.48	0.013	0.016	0.019		
b1	0.44	0.51	0.58	0.017	0.020	0.023		
b2	4.80	4.90	5.00	0.189	0.193	0.197		
b3		0.094			0.004			
b4		0.47			0.019			
С	0.20	0.25	0.30	0.008	0.010	0.012		
D	5.00	5.13	5.25	0.197	0.202	0.207		
D1	4.80	4.90	5.00	0.189	0.193	0.197		
D2	3.86	3.96	4.06	0.152	0.156	0.160		
D3	1.63	1.73	1.83	0.064	0.068	0.072		
е		1.27 BSC		0.050 BSC				
Е	6.05	6.15	6.25	0.238	0.242	0.246		
E1	4.27	4.37	4.47	0.168	0.172	0.176		
E2	2.75	2.85	2.95	0.108	0.112	0.116		
E3	6.05	6.22	6.40	0.238	0.245	0.252		
F	-	-	0.15	-	-	0.006		
L	0.62	0.72	0.82	0.024	0.028	0.032		
L1	0.92	1.07	1.22	0.036	0.042	0.048		
K		0.51			0.020			
W		0.23			0.009			
W1		0.41			0.016			
W2	2.82			0.111				
W3		2.96			0.117			
θ	0°	-	10°	0°	-	10°		

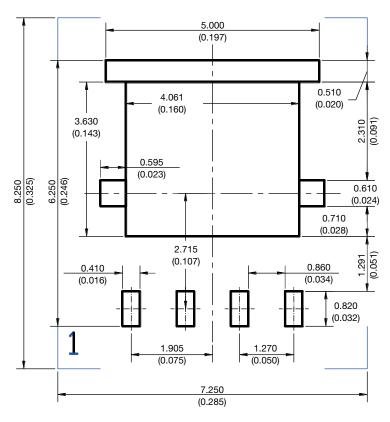
DWG: 6044

Note

• Millimeters will govern



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L SINGLE



Recommended Minimum Pads Dimensions in mm (inches)



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